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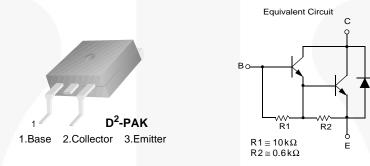
December 2014



FJB102 NPN High-Voltage Power Darlington Transistor

Features

- High DC Current Gain : h_{FE} = 1000 at V_{CE} = 4 V, I_C = 3 A (Minimum)
- Low Collector-Emitter Saturation Voltage



Ordering Information

Part Number	Top Mark	Package	Packing Method
FJB102TM	FJB102	TO-263 2L (D2PAK)	Tape and Reel

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_c = 25^{\circ}C$ unless otherwise noted.

Symbol Parameter		Value	
V _{CBO}	Collector-Base Voltage	100	V
V _{CEO}	Collector-Emitter Voltage	100	V
V _{EBO}	Emitter-Base Voltage	5	V
Ι _C	Collector Current (DC)	8 15	
I _{CP}	Collector Current (Pulse) ⁽¹⁾		
Ι _Β	Base Current (DC)	1	А
P_{C} Collector Dissipation ($T_{C} = 25^{\circ}C$)		80	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature Range	-65 to 150	°C

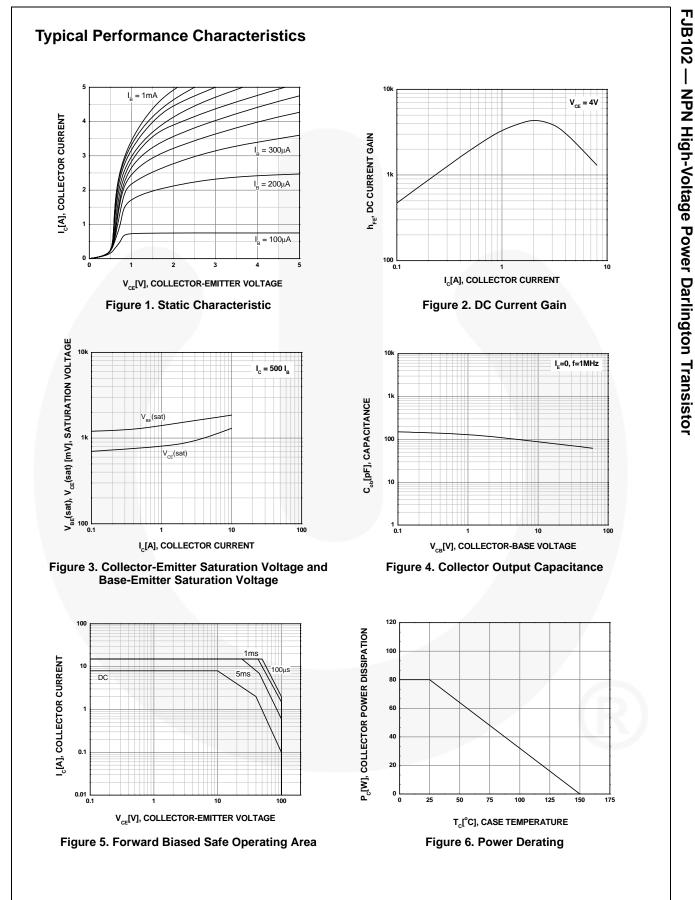
Note:

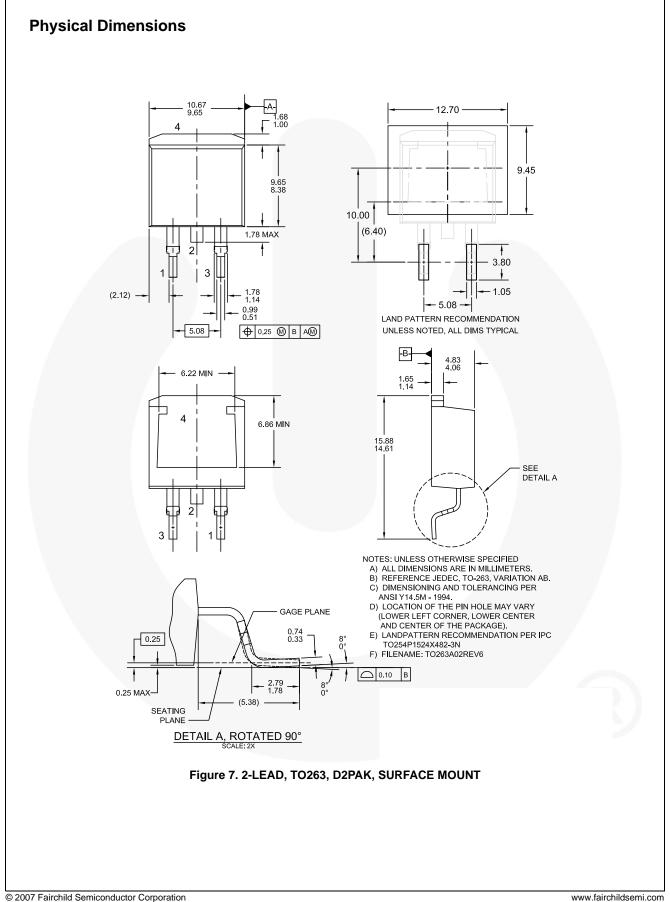
1. Pulse test: $pw \le 300 \ \mu s$, duty cycle $\le 2\%$.

Electrical Characteristics

Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
BV _{CEO} (sus)	Collector-Emitter Sustaining Voltage	I _C = 30 mA, I _B = 0	100		V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 500 μA, I _C = 0	10		V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 100 \text{ V}, I_{E} = 0$		50	μA
I _{CEO}	Collector Cut-Off Current	$V_{CE} = 50 \text{ V}, \text{ I}_{B} = 0$		50	μA
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 5 V, I_{C} = 0$		2	mA
h _{FE}	DC Current Gain	$V_{CE} = 4 V, I_{C} = 3 A$	1000	20000	
		$V_{CE} = 4 V, I_{C} = 8 A$	200		
V _{CE} (sat)		$I_{\rm C} = 3 \text{ A}, I_{\rm B} = 6 \text{ mA}$		2.0	V
	Collector-Emitter Saturation Voltage	I _C = 8 A, I _B = 80 mA		2.5	v
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 4 V, I_{C} = 8 A$		2.8	V
C _{ob}	Output Capacitance	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0,$ f = 1 MHz		200	pF





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Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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